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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









# 78 Series Regulators

# 1A Output 78 series Regulators 500mA Output 78 series Regulators





No.12019ECT01

# BA78□□Series,BA78M□□Series

#### Description

#### Features

- 1) Built-in over-current protection circuit and thermal shutdown circuit
- 2) High ripple rejection
- 3) Available TO220CP-3, TO252-3 package to a wide range application
- 4) Compatible replacement to competitor products
- 5) Various voltage lineup (5V, 6V, 7V, 8V, 9V, 10V, 12V, 15V, 18V, 20V, 24V)

#### Applications

Fixed voltage power supply for TV, Audio components, etc

#### ●Line up

#### ■1A BA78□□Series

Part Number	5V	6V	7V	8V	9V	10V	12V	15V	18V	20V	24V	Package
ВА78□□СР	0	0	0	0	0	0	0	0	0	0	0	TO220CP-3
BA78□□FP	0	0	0	0	0	0	0	0	0	0	0	TO252-3

#### ■0.5A BA78M□□Series

<b>2</b> 0.07 C D7 (7 O) (1 C		<del></del>										
Part Number	5V	6V	7V	8V	9V	10V	12V	15V	18V	20V	24V	Package
BA78M□□CP	0	0	0	0	0	0	0	0	0	0	0	TO220CP-3
BA78M□□FP	0	0	0	0	0	0	0	0	0	0	0	TO252-3

# Output Voltage and Marking

Symbol		assignment of	output	voltage
		Output voltage(V)		Output voltage(V)
	05	5.0V typ.	12	12V typ.
	06	6.0V typ.	15	15V typ.
а	07	7.0V typ.	18	18V typ.
	08	8.0V typ.	20	20V typ.
	09	9.0V typ.	24	24V typ.
	10	10.0V typ.		
		Package		
		CP : TO220C	P-3	
b		FP : TO252-3		

Symbol		assignment o	f outpu	ıt voltage
		Output voltage(V)		Output voltage(V)
	05	5.0V typ.	12	12V typ.
	06	6.0V typ.	15	15V typ.
а	07	7.0V typ.	18	18V typ.
	08	8.0V typ.	20	20V typ.
	09	9.0V typ.	24	24V typ.
	10	10.0V typ.		
	ı	Package		
		CP : TO220	CP-3	
b		FP : TO252-	3	

# ● Absolute Maximum Rating (Ta=25°C) BA78□□CP/FP, BA78М□□CP/FP

Parameter Symbol Limits Unit Power supply voltage Vin 35 TO220CP-3 2 W Power Dissipation 1 Pd1 TO252-3 1 22 TO220CP-3 Pd2 Power Dissipation 2 W TO252-3 10 1 \*3 BA78□□ **Output Current** Α lo 0.5 \*3 BA78□□M °C Operating Temperature Range Topr -40~+85 Storage Temperature Range Tstg -55~+150 °C

- \*1 Derating in done 16mW/°C(TO220CP-3), 8mW/°C(TO252-3) for temperatures above Ta=25°C
- \*2 Derating in done 176mW/°C(TO220CP-3), 80mW/°C(TO252-3) for temperatures above Ta=25°C, Mounted on infinity Alminium heat sink.

Τj

\*3 Pd,ASO and Tjmax(150°C) should not be exceeded.

Operating Junction Temperature Range

#### Operating Conditions(Ta=25°C, Pd should not be exceeded) BA78□□CP/FP

Par	ameter	Symbol	Min.	Max.	Unit.
1 an	BA7805	Cyllibol	7.5	25	OTIL.
	BA7806		8.5	21	
	BA7807		9.5	22	
	BA7808		10.5	23	
lana	BA7809		11.5	26	
Input Voltage	BA7810	Vin	12.5	25	V
voltage	BA7812		14.5	27	
	BA7815		17.5	30	
	BA7818		21	33	
	BA7820		23	33	
	BA7824		27	33	
Output C	urrent	lo	-	1	Α

#### BA78M□□CP/FP

-40~+150

Par	ameter	Symbol	Min.	Max.	Unit.
	BA78M05		7.5	25	
	BA78M06		8.5	21	
	BA78M07		9.5	22	
	BA78M08		10.5	23	
loout	BA78M09		11.5	26	
Input Voltage	BA78M10	Vin	12.5	25	V
vollage	BA78M12		14.5	27	
	BA78M15		17.5	30	
	BA78M18		21	33	
	BA78M20		23	33	
	BA78M24		27	33	
Output C	urrent	lo	-	0.5	Α

°С

# ● Electrical Characteristics BA78M□□CP/FP

 $(Ta = 25^{\circ}\text{C}, Vin = 10V(05), 11V(06), 13V(07), 14V(08), 15V(09), 16V(10), 19V(12), 23V(15), 27V(18), 29V(20), 33V(24), \ lo = 350\text{mA unless otherwise specified})$ 

(1a=25 C, VIII=10 V(05), 11 V(06	5),13 (07),14 (0	6), 15 (09), 16 (10), 19 (12),23 (	/(15),2/V(16)	,291(20),331	(24), 10 – 350	ma uniess ou	lerwise specified)
Parameter	Symbol	Туре	Min	Limit Typ	Max	Unit	Condition
		05	4.8	5.0	5.2		
		06	5.75	6.0	6.25		
		07	6.7	7.0	7.3		
		08	7.7	8.0	8.3		
		09	8.6	9.0	9.4		
Output Voltage 1	Vo1	10	9.6	10.0	10.4	V	lo=350mA
		12	11.5	12.0	12.5		
		15	14.4	15.0	15.6		
		18	17.3	18.0	18.7		
		20	19.2	20.0	20.8		
		24	23.0	24.0	25.0		
		05	4.75	-	5.25		Vin=7.5~20V, Io=5mA~350mA
		06	5.7	-	6.3		Vin=8.5~21V, Io=5mA~350mA
		07	6.65	-	7.35		Vin=9.5~22V, Io=5mA~350mA
		08	7.6	-	8.4		Vin=10.5~23V, Io=5mA~350mA
		09	8.55	-	9.45		Vin=11.5~24V, Io=5mA~350mA
Output Voltage 2	Vo2	10	9.5	-	10.5	V	Vin=12.5~25V, lo=5mA~350mA
		12	11.4	-	12.6		Vin=15~27V, Io=5mA~350mA
		15	14.25	-	15.75		Vin=17.5~30V, lo=5mA~350mA
		18	17.1	-	18.9		Vin=21~33V, lo=5mA~350mA
		20 24	19.0 22.8	-	21.0 25.2		Vin=23~33V, Io=5mA~350mA
		05	- 22.8	3	100		Vin=27~33V, Io=5mA~350mA Vin=7~25V, Io=200mA
		06	-	3	100		Vin=8~25V, Io=200mA
		07	-	4	100		Vin=9~25V, Io=200mA
		08	-	4	100		Vin=10.5~25V, Io=200mA
		09	_	4	100		Vin=11.5~26V, Io=200mA
Line Regulation 1	Reg.I1	10	-	5	100	mV	Vin=12.5~28V, lo=200mA
o	1.09	12	-	5	100	1	Vin=14.5~30V, lo=200mA
		15	-	6	100		Vin=17.5~30V, lo=200mA
		18	-	7	100		Vin=21~33V, Io=200mA
		20	-	8	100		Vin=23~33V, Io=200mA
		24	-	10	100		Vin=27~33V, Io=200mA
		05	-	1	50		Vin=8~12V, Io=200mA
		06	-	1	50		Vin=9~25V, Io=200mA
		07	-	1	50		Vin=10~25V, Io=200mA
		08	-	1	50		Vin=11~25V, Io=200mA
		09	-	2	50		Vin=12~25V, Io=200mA
Line Regulation 2	Reg.I2	10	-	2	50	mV	Vin=14~26V, Io=200mA
		12	-	3	50		Vin=16~30V, Io=200mA
		15	-	3	50		Vin=20~30V, lo=200mA
		18	-	3	50		Vin=24~33V, Io=200mA
		20	-	4	50		Vin=24~33V, Io=200mA
		24 05	62	5 78	50		Vin=28~33V, Io=200mA
		06	60	78	-	-	
		06	57	74	-	}	
		08	56	69	-	-	
		09	56	67	-	1	
Ripple Rejection	R.R.	10	56	66	_	dB	ein=1Vrms, f=120Hz, Io=100mA
		12	55	63	-	"5	
		15	54	60	-	1	
		18	53	58	-		
		20	53	58	-	1	
		24	50	55	-	<u> </u>	
Tomporatura		05	-	-1.0	-		
Temperature Coefficient of	Tcvo	06/07/08/09/10/12	-	-0.5	-	mV/°C	lo=5mA, Tj=0~125°C
Output Voltage	1000	15/18	-	-0.6	-	111 V/C	10-511A, 1j=0.5125 C
		20/24	-	-0.7	-		
Peak Output Current	lo-p	common	-	875	-	mA	Tj=25°C
Dropout Voltage	Vd	common	-	2.0	-	V	lo=500mA

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# ● Electrical Characteristics BA78M□□CP/FP

 $(Ta=25^{\circ}C, Vin=10V(05), 11V(06), 13V(07), 14V(08), 15V(09), 16V(10), 19V(12), 23V(15), 27V(18), 29V(20), 33V(24), lo=350 mA unless otherwise specified)$ 

Parameter	Symbol	Туре	Min	Limit Typ	Max	Unit	Condition
		05	-	20	100		
		06	-	20	120		
		07	-	20	140		
		08	-	20	160		
		09	-	20	180		
Load Regulation 1	Reg.L1	10	-	20	200	mV	Io=5mA~500mA
ŭ		12	-	20	240		
		15	-	20	300		
		18	-	20	360		
		20	-	20	400		
		24	-	20	480		
		05	_	10	50		
		06	_	10	60		
		07	_	10	70		
		08	-	10	80		
			<b>†</b>				
Laad Damidatian O	Dec 10	09	-	10	90	\/	In Fire A
Load Regulation 2	Reg.L2	10	-	10	100	mV	lo=5mA~200mA
		12	-	10	120		
		15	-	10	150		
		18	-	10	180		
		20	-	10	200		
		24	-	10	240		
		05	-	40	-		
		06	-	60	-		
		07	-	70	-		
		08	-	80	-		
0		09	-	90	-		
Output Noise	Vn	10	-	100	-	μV	f=10Hz~100kHz
Voltage		12	-	110	-	•	
		15	-	130	-		
		18	-	140	-		
		20	-	150	-		
		24	_	170	_		
Bias Current	lb	common	-	4.5	6.0	mA	lo=0mA
Bias Current Change1	lb1	common	-	-	0.5	mA	lo=5mA~350mA
Dias Guiterit Griange i	101	05	-	-	0.8	ША	Vin:8~25V, Io=200mA
		06		_	0.8		Vin:9~25V, Io=200mA
		07	-		0.8		
			-	-			Vin:10~25V, lo=200mA
		08	-	-	0.8		Vin:10.5~25V, lo=200mA
D' O O O	11-0	09	-	-	0.8		Vin:12~25V, lo=200mA
Bias Current Change 2	lb2	10	-	-	0.8	mA	Vin:13~25V, lo=200mA
		12	-	-	0.8		Vin:14.5~30V, lo=200mA
		15	-	-	0.8		Vin:17.5~30V, lo=200mA
		18	-	-	0.8		Vin:21~33V, lo=200mA
		20	-	-	0.8		Vin:23~33V, Io=200mA
		24	-	-	0.8		Vin:27~33V, Io=200mA
Short-Circuit	los	05/06/07/08	-	0.4	-	Α	Vin=25V
Output Current	.55	09/10/12/15/18/20/24	-	0.17	-	,,	Vin=30V
		05	-	9	-		
		06	-	10	-		
		07	-	11	-		
		08	-	12	-		
		09		13	-		
Output Resistance	Ro	10	-	14	-	mΩ	f=1kHz
		12	-	16	-		
	1		-				
		15	-	1 19			
		15 18	-	19 22	-		
		15 18 20	-	22 25	-		

# ● Electrical Characteristics BA78□□CP/FP

 $(Ta=25^{\circ}C, Vin=10V(05), 11V(06), 13V(07), 14V(08), 15V(09), 16V(10), 19V(12), 23V(15), 27V(18), 29V(20), 33V(24), lo=500 mA \ unless \ otherwise \ specified)$ 

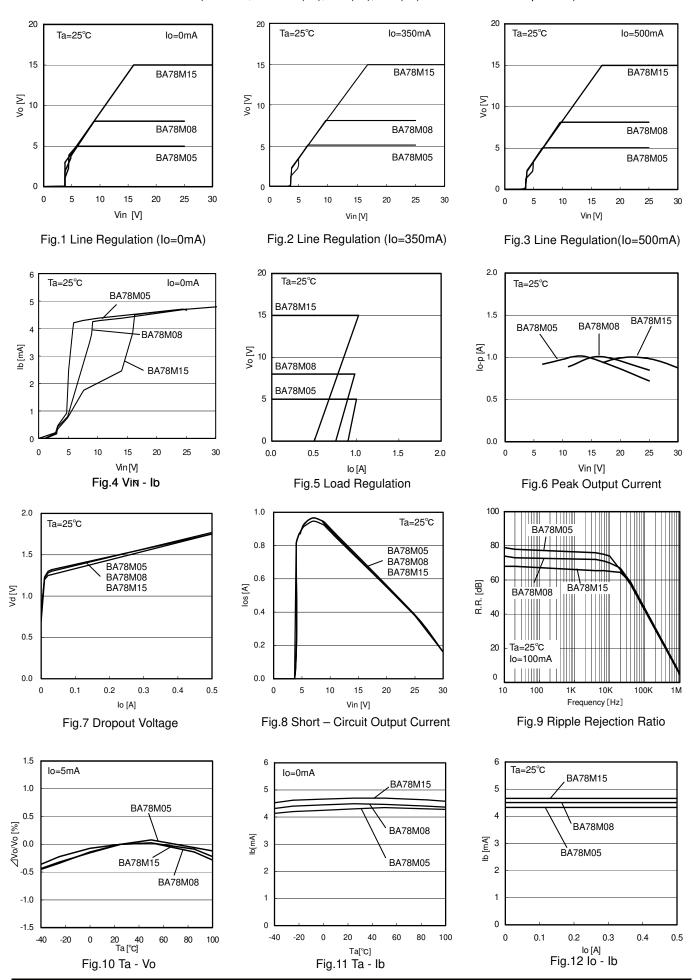
Parameter	Symbol	Type		Limit	1	Unit	Condition
T drameter	Cyrribor	• •	Min	Тур	Max	Offic	Condition
		05	4.8	5.0	5.2		
		06 07	5.75 6.7	6.0	6.25		
		08	7.7	7.0 8.0	7.3 8.3		
		09	8.6	9.0	9.4		
Output Voltage 1	Vo1	10	9.6	10.0	10.4	V	Io=500mA
output Tottago .		12	11.5	12.0	12.5	•	
		15	14.4	15.0	15.6		
		18	17.3	18.0	18.7		
		20	19.2	20.0	20.8		
		24	23.0	24.0	25.0		
		05	4.75	-	5.25		Vin=7.5~20V, Io=5mA~1A
		06	5.7	-	6.3		Vin=8.5~21V, Io=5mA~1A
		07	6.65	-	7.35		Vin=9.5~22V, Io=5mA~1A
		08	7.6	-	8.4		Vin=10.5~23V, lo=5mA~1A
Output Voltage 2	Vo2	09 10	8.55 9.5	-	9.45 10.5	V	Vin=11.5~26V, lo=5mA~1A
Output voltage 2	VUZ	12	11.4	-	12.6	v	Vin=12.5~25V, lo=5mA~1A Vin=15~27V, lo=5mA~1A
		15	14.25	-	15.75		Vin=17.5~30V, lo=5mA~1A
		18	17.1	-	18.9		Vin=21~33V, Io=5mA~1A
		20	19.0	-	21.0		Vin=23~33V, Io=5mA~1A
		24	22.8	-	25.2	<u> </u>	Vin=27~33V, Io=5mA~1A
		05	-	3	100		Vin=7~25V, Io=500mA
		06	-	4	120		Vin=8~25V, Io=500mA
		07	-	5	140		Vin=9~25V, Io=500mA
		08	-	5	160		Vin=10.5~25V, Io=500mA
	D 14	09	-	6	180	,,	Vin=11.5~26V, lo=500mA
Line Regulation 1	Reg.I1	10	-	7	200	mV	Vin=12.5~27V, Io=500mA
		12 15	-	8 9	240 300		Vin=14.5~30V, Io=500mA Vin=17.5~30V, Io=500mA
		18	-	10	360		Vin=21~33V, lo=500mA
		20	_	12	400		Vin=23~33V, Io=500mA
		24	-	15	480		Vin=27~33V, Io=500mA
		05	-	1	50		Vin=8~12V, Io=500mA
		06	-	2	60		Vin=9~13V, Io=500mA
		07	-	2	70		Vin=10~15V, Io=500mA
		08	-	3	80		Vin=11~17V, Io=500mA
		09	-	4	90		Vin=13~19V, Io=500mA
Line Regulation 2	Reg.l2	10	-	4	100	mV	Vin=14~20V, Io=500mA
		12	-	5	120		Vin=16~22V, lo=500mA
		15	-	5	150		Vin=20~26V, lo=500mA
		18 20	<del>-</del>	5 7	180 200		Vin=24~30V, Io=500mA Vin=26~32V, Io=500mA
		24	-	10	240		Vin=26~32V, 10=500mA Vin=30~33V, 10=500mA
		05	62	78	-		VIII-00 - 30 V, 10=300111A
		06	59	73	-		
		07	57	69	-		
		08	56	65	-		
		09	56	64	-	]	oin 1)/rmo f 10011-
Ripple Rejection	R.R.	10	55	64	-	dB	ein=1Vrms, f=120Hz, Io=100mA
		12	55	63	-		io-Toomia
		15	54	62	-		
		18	53	61	-		
		20	53	60	-		
	-	24	50	58	-		
Temperature		05 06/07/08/09/10/12	-	-1.0	-		
Coefficient of	Tcvo	15/18	-	-0.5 -0.6	-	mV/°C	lo=5mA, Tj=0~125°C
Output Voltage		20/24	-	-0.6	-		
Peak Output Current	lo-p	common	-	1.7	-	Α	Tj=25°C
Dropout Voltage	Vd	common	-	2.0	-	V	lo=1A
spour voitage		33.1.111011	ļ				1.0

# ●Electrical Characteristics BA78□□CP/FP

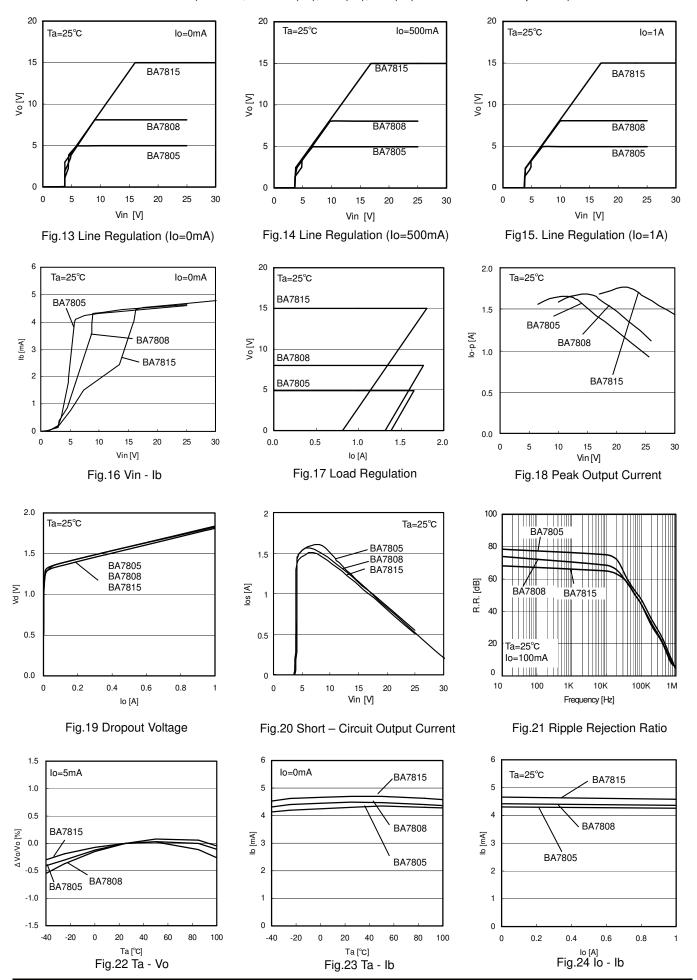
 $(Ta=25^{\circ}C, Vin=10V(05), 11V(06), 13V(07), 14V(08), 15V(09), 16V(10), 19V(12), 23V(15), 27V(18), 29V(20), 33V(24), lo=500 mA \\ unless otherwise specified)$ 

Parameter   Symbol   Type   Min   Typ   Max   Min   Typ   Max	Condition  Io=5mA~1A  Io=250mA~750mA
Load Regulation 1   Reg.L1   Reg.L1   Reg.L1   10   10   10   10   10   10   10	
Load Regulation 1   Reg.L1   10   -   16   120   140   160   180   190   180   190   180   190   180   190   180   190   180   190   180   190   180   190   180   190   190   190   180   19	
Load Regulation 1  Reg.L1  Reg.L1  Reg.L1  Reg.L1  Reg.L1  Reg.L1  Reg.L1  Reg.L2  Reg	
Reg.L1   Reg.L1   10   -   21   200   mV	
Load Regulation 1  Reg.L1  Reg.L1  10	
Load Regulation 1   Reg.L1   10   -   21   200   mV     12   -   23   200     15   -   27   300     18   -   30   360     20   -   32   400     24   -   37   480     24   -   37   480     25   -   5   50     06   -   6   60     07   -   6   70     08   -   7   80     099   -   8   90     12   -   10   100     15   -   10   150     18   -   12   180     20   -   14   200     24   -   15   240     Output Noise     Voltage   Voltage   Voltage   Voltage     Bias Current   Ib   common   -   4.5   8.0   mA	
12	
15	lo=250mA~750mA
18	lo=250mA~750mA
20	lo=250mA~750mA
24	lo=250mA~750mA
Note	lo=250mA~750mA
Note	lo=250mA~750mA
Note	lo=250mA~750mA
Reg.L2   Reg.L2   Reg.L2   10	lo=250mA~750mA
Reg.L2   Reg.L2   10   -   8   90   mV	lo=250mA~750mA
Load Regulation 2   Reg.L2   10	lo=250mA~750mA
Load Regulation 2   Reg.L2   10   -   8   90   mV     12   -   10   100     15   -   10   150     18   -   12   180     20   -   14   200     24   -   15   240     24   -   15   240     24   -   15   240     05   -   40   -     06   -   60   -     07   -   70   -     08   -   80   -     09   -   90   -     09   -   90   -     10   -   100   -     12   -   110   -     15   -   125   -     18   -   140   -     20   -   150   -     24   -   180   -     Bias Current   Ib   common   -   4.5   8.0   mA	lo=250mA~750mA
12	10=25UMA~/5UMA
15	
18	
20	
24     -     15     240       05     -     40     -       06     -     60     -       07     -     70     -       08     -     80     -       09     -     90     -       100     -       12     -     110     -       15     -     125     -       18     -     140     -       20     -     150     -       24     -     180     -       Bias Current     Ib     common     -     4.5     8.0     mA	
05       -       40       -         06       -       60       -         07       -       70       -         08       -       80       -         09       -       90       -         10       -       100       -         12       -       110       -         15       -       125       -         18       -       140       -         20       -       150       -         24       -       180       -         Bias Current       Ib       common       -       4.5       8.0       mA	
05       -       40       -         06       -       60       -         07       -       70       -         08       -       80       -         09       -       90       -         10       -       100       -         12       -       110       -         15       -       125       -         18       -       140       -         20       -       150       -         24       -       180       -         Bias Current       Ib       common       -       4.5       8.0       mA	
Output Noise Voltage  Vn  06	
Output Noise Voltage  Vn  10  10  10  10  10  110  110  110	
Output Noise Voltage  Vn  10  10  12  110  15  125  18  18  140  20  180  Bias Current  Nn  Nn  Nn  Nn  Nn  Nn  Nn  Nn  Nn	
Output Noise Voltage     Vn     10     -     90     -       12     -     110     -       15     -     125     -       18     -     140     -       20     -     150     -       24     -     180     -       Bias Current     Ib     common     -     4.5     8.0     mA	
Voltage     Vn     10     -     100     -       12     -     110     -       15     -     125     -       18     -     140     -       20     -     150     -       24     -     180     -       Bias Current     Ib     common     -     4.5     8.0     mA	
Voltage    VII	
12	f=10Hz~100kHz
18	
20     -     150     -       24     -     180     -       Bias Current     lb     common     -     4.5     8.0     mA	
24         -         180         -           Bias Current         Ib         common         -         4.5         8.0         mA	
24         -         180         -           Bias Current         Ib         common         -         4.5         8.0         mA	
Bias Current Ib common - 4.5 8.0 mA	
	Io=0mA
Bias Current Change 1   Ib1   common   -   -   0.5   mA	Io=5mA~1A
05 0.8	Vin:8~25V, Io=500mA
06 0.8	Vin:8.5~25V, lo=500mA
07 0.8	Vin:9.5~25V, lo=500mA
08 0.8	Vin:10.5~25V, Io=500mA
09 0.8	Vin:11.5~26V, Io=500mA
Bias Current Change 2 lb2 10 - 0.8 mA	Vin:12.5~27V, Io=500mA
12 - 0.8	Vin:14.5~30V, lo=500mA
15 0.8	Vin:17.5~30V, lo=500mA
18 0.8	Vin:21~33V, Io=500mA
20 0.8	Vin:23~33V, Io=500mA
24 0.8	Vin:27~33V, Io=500mA
Short-Circuit 05/06/07/08 - 0.6 -	Vin=25V
Output Current Ios 09/10/12/15/18/20/24 - 0.3 - A	Vin=25V Vin=30V
Output Current 09/10/12/15/18/20/24 - 0.3 -	VIII=3UV
05 - 9 -	
06 10 -	
07 10 -	
08 10 -	
09 - 10 -	İ
Output Resistance Ro 10 - 11 - mΩ	
12 - 12 -	f=1kHz
	f=1kHz
	f=1kHz
15 - 14 -	f=1kHz
	f=1kHz

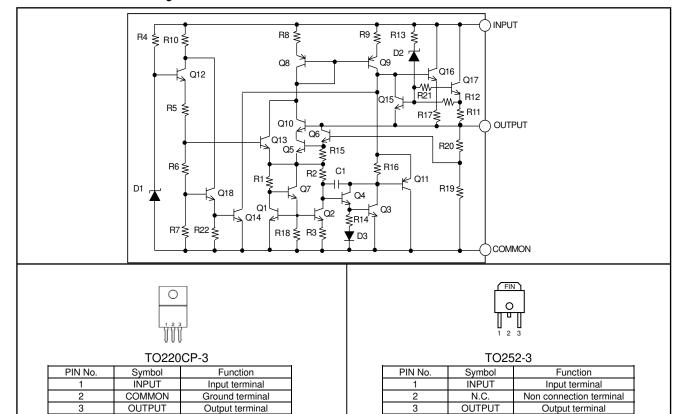
# ●BA78M□□ Characteristics data(Ta=25°C, Vin=10V(05), 14V(08), 23V(15) unless otherwise specified)



#### ●BA78□□ Characteristics data (Ta=25°C, Vin=10V(05), 14V(08), 23V(15) unless otherwise specified)



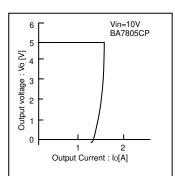
#### ●Internal Circuit Structural Diagram



#### Protection Circuit

# (1)Over-current protection circuit

When the maximum rating current or more is rushed, it controls the current ability and protects the IC from destruction.

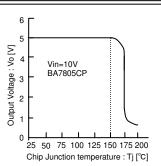


Ground terminal

COMMON

# (2) Thermal shutdown circuit

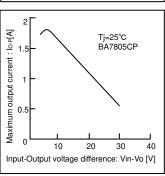
When the chip temperature of IC exceeds the setting temperature, the IC goes OFF, and it controls the IC not to be destroyed by the heat generation. It can be restored by being lowered the chip temperature of IC below the setting temperature.



#### (3) Safety operation area control circuit

It controls the output current in inverse proportion ratio to voltage difference (input-output).

When voltage difference becomes bigger, the IC will be destroyed in rush current. It protects the IC by controlling the current ability according to the voltage level.



#### Thermal design

Refer to the following thermal derating curves (Fig. 25, 26), when using in the status of Ta=25°C or more.

The characteristic of IC is greatly related to the operating temperature.

When it is used in over maximum junction temperature, the elements inside IC might become weaker and be destroyed. It is recommended to take into consideration thermal of IC.

Note that the temperatures are in the allowed temperature limits and operated within Pd.

It is necessary to operate it at junction temperature Timax or less to prevent IC from the thermal destruction.

Please operate IC within permissible loss Pd because the junction temperature Tj might become considerably a high temperature even if ambient temperature Ta is normal temperature (25°C).

Power consumption Pc(W) may be expressed by the equation shown below:

 $Pc=(Vin-Vo) \times Io+ Vin \times Ib$ permissible loss  $Pd \ge Pc$ 

 $lo \le \frac{Pd - Vin \times lb}{Vin - Vo}$ 

Vin : Input Voltage
Vo : Output Voltage
Io : Output Current
Ib : Bias current

Maximum Output current lo<sub>MAX</sub> can be calculated in thermal design.

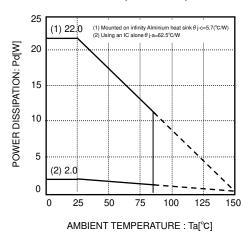
· Calculation example

Ex.1) 
$$Ta=85^{\circ}C$$
,  $Vin = 7.5V$ ,  $Vo=5.0V$ 

$$lo \le \frac{1.04 - 7.5 \times 4.5m}{7.5 - 5.0}$$
  
 $lo \le 400 mA$ 

Using TO220CP-3 alone  $\theta$  ja=62.5°C/W $\rightarrow$ 16mW/°C Pd=1.04W at 85°C

Be sure to use this IC within a power dissipation at the range of operating temperature.



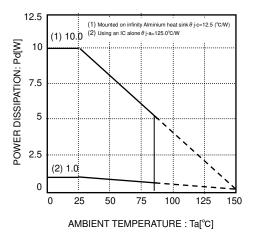


Fig.25 Thermal derating curve (TO220CP-3)

Fig.26 Thermal derating curve (TO252-3)

#### Terminal Setting and Cautions

#### INPUT

It is recommended that a capacitor (about 0.33uF) be inserted between INPUT and COMMON. The value of capacitor is designed suitable for the actual application.

#### OUTPUT

It is recommended that a capacitor (about 0.1uF) be inserted between OUTPUT and COMMON.

A tantalum capacitor can also be used for this pin because insufficient capacitors may cause oscillation by a temperature change.

#### COMMON

Keep the no voltage drop between Ground level of set board and IC.

When there is the voltage difference, setting voltage becomes inaccuracy and unstable.

It is recommended to connect by wide, short pattern, and lower the inpedance.

#### Notes for use

(1) Absolute Maximum Ratings

While utmost care is taken to quality control of this product, any application that may exceed some of the absolute maximum ratings including the voltage applied and the operating temperature range may result in breakage. If broken, short-mode or open-mode may not be identified. So if it is expected to encounter with special mode that may exceed the absolute maximum ratings, it is requested to take necessary safety measures physically including insertion of fuses.

(2) Ground voltage

Make setting of the potential of the GND terminal so that it will be maintained at the minimum in any operating state. Furthermore, check to be sure no terminals are at a potential lower than the GND voltage including an actual electric transient.

(3) Thermal design

When you do the kind of use which exceeds Pd, It may be happened to deteriorating IC original quality such as decrease of electric current ability with chip temperature rise. Do not exceed the power dissipation (Pd) of the package specification rating under actual operation, and please design enough temperature margins.

(4) Short-circuiting between terminals, and mismounting

When mounting to pc board, care must be taken to avoid mistake in its orientation and alignment. Failure to do so may result in IC breakdown. Short-circuiting due to foreign matters entered between output terminals, or between output and power supply or GND may also cause breakdown.

(5) Operation in Strong electromagnetic field

Be noted that using the IC in the strong electromagnetic radiation can cause operation failures.

(6) Inspection with the IC set to a pc board

If a capacitor must be connected to the pin of lower impedance during inspection with the IC set to a pc board, the capacitor must be discharged after each process to avoid stress to the IC. For electrostatic protection, provide proper grounding to assembling processes with special care taken in handling and storage. When connecting to jigs in the inspection process, be sure to turn OFF the power supply before it is connected and removed.

(7) Input to IC terminals

This is a monolithic IC with P<sup>+</sup> isolation between P-substrate and each element as illustrated below. This P-layer and the N-layer of each element form a P-N junction, and various parasitic element are formed.

If a resistor is joined to a transistor terminal as shown in Fig 28.

OP-N junction works as a parasitic diode if the following relationship is satisfied;

GND>Terminal A (at resistor side), or GND>Terminal B (at transistor side); and

Oif GND>Terminal B (at NPN transistor side),

a parasitic NPN transistor is activated by N-layer of other element adjacent to the above-mentioned parasitic diode. The structure of the IC inevitably forms parasitic elements, the activation of which may cause interference among circuits, and/or malfunctions contributing to breakdown. It is therefore requested to take care not to use the device in such manner that the voltage lower than GND (at P-substrate) may be applied to the input terminal, which may result in activation of parasitic elements.

(8) Ground wiring pattern

If small-signal GND and large-current GND are provided, It will be recommended to separate the large-current GND pattern from the small-signal GND pattern and establish a single ground at the reference point of the set PCB so that resistance to the wiring pattern and voltage fluctuations due to a large current will cause no fluctuations in voltages of the small-signal GND. Pay attention not to cause fluctuations in the GND wiring pattern of external parts as well.

(9) Thermal shutdown circuit

A temperature control circuit is built in the IC to prevent the damage due to overheat. Therefore, the output is turned off when the thermal circuit works and is turned on when the temperature goes down to the specified level.

But, built-in the IC a temperature control circuit to protect itself, and avoid the design used the thermal protection.

(10) Over current protection circuit

The over-current protection circuits are built in at output, according to their respective current outputs and prevent the IC from being damaged when the load is short-circuited or over-current. But, these protection circuits are effective for preventing destruction by unexpected accident. When it's in continuous protection circuit moving period don't use please. And for ability, because this chip has minus characteristic, be careful for heat plan.

(11) There is a possibility to damage an internal circuit or the element when Vin and the voltage of each terminal reverse in the application. For instance, Vin is short-circuited to GND etc. with the charge charged to an external capacitor. Please use the capacitor of the output terminal with 1000µF or less. Moreover, the Vin series is recommended to insert the diode of the by-pass the diode of the backflow prevention or between each terminal and Vin.

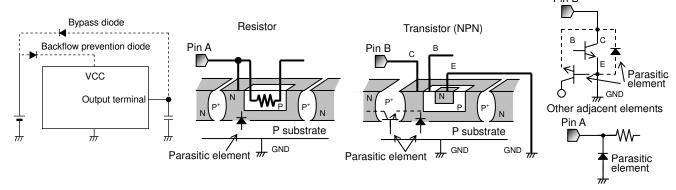
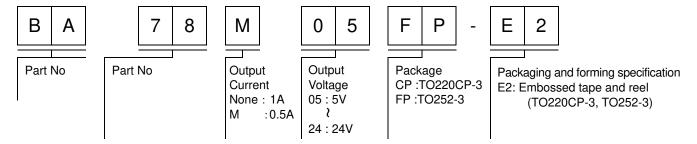


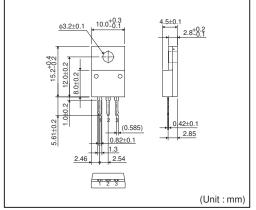
Fig.27 Bypass Diode

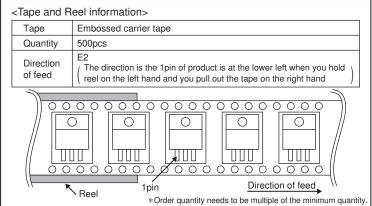
Fig.28 Simplified structure of monorisic IC

# Ordering part number

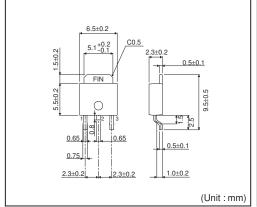


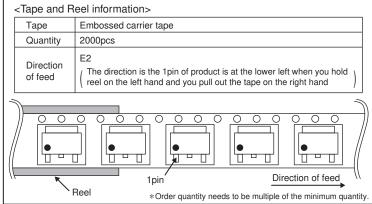
#### TO220CP-3





# TO252-3





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